TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74ACT153P, TC74ACT153F, TC74ACT153FN

DUAL 4 - CHANNEL MULTIPLEXER

The TC74ACT153 is an advanced high speed CMOS DUAL 4 - CHANNEL MULTIPLEXERs fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipations.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

Each of these data $(1C0 - 1C3, \ 2C0 - 2C3)$ is selected by the two address inputs A and B.

Separate strobe inputs $(1\overline{G}, 2\overline{G})$ are provided for each of the two four-line sections.

The strobe input can be used to inhibit the data output; the output is fixed in low level unconditionally.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed-----tpd = 5.4ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ··············· $I_{CC} = 8\mu A(Max.)$ at Ta = 25°C
- Compatible with TTL outputs $\cdots V_{1L} = 0.8V$ (Max.)

 $V_{1H} = 2.0V (Min.)$

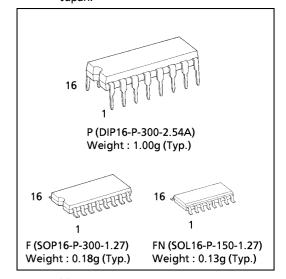
• Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 24\text{mA}(Min.)$ Capability of driving 50Ω

transmission lines.

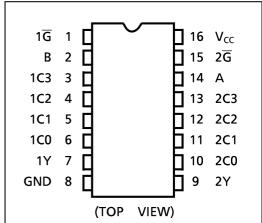
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- Balanced Propagation Delays $\cdots t_{pLH} \approx t_{pHL}$
- Pin and Function Compatible with 74F153

(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT

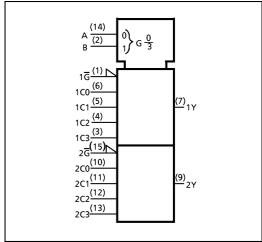


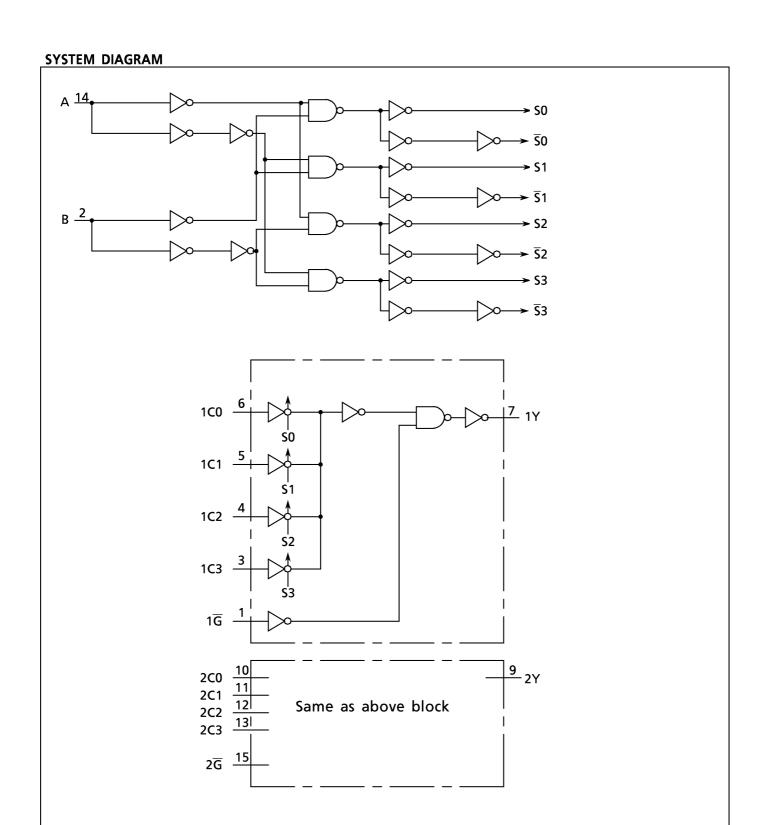
TRUTH TABLE

	SELECT INPUTS		DATA	STROBE	ОИТРИТ			
В	Α	C0	C1	C2	C 3	G	Υ	
Х	Х	Х	Х	Х	Χ	Н	L	
L	L	L	Х	Х	Х	L	L	
L	L	Н	Х	Х	Х	L	Н	
L	Н	Х	L	Х	Х	L	L	
L	Н	Х	Η	Х	Х	L	Н	
Н	L	Х	Х	L	Х	L	L	
Н	L	Х	Х	Н	Х	L	Н	
Н	Н	Х	Х	Х	L	L	L	
Н	Н	Х	Х	Х	Н	L	Н	

X: Don't Care

IEC LOGIC SYMBOL





ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V _{cc}	-0.5~7.0	٧
DC Input Voltage	V _{IN}	$-0.5 \sim V_{CC} + 0.5$	>
DC Output Voltage	V _{OUT}	−0.5~V _{CC} + 0.5	٧
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 50	mA
DC Output Current	I _{OUT}	± 50	mA
DC V _{CC} /Ground Current	I _{cc}	± 100	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

^{*500}mW in the range of Ta = -40° C \sim 65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V _{IN}	0~V _{CC}	V
Output Voltage	V _{OUT}	0~V _{cc}	V
Operating Temperature	Topr	−40~85	°C
Input Rise and Fall Time	dt/dV	0~10	ns / V

DC ELECTRICAL CHARACTERISTICS

DADAMETER			[Т	a = 25°0	<u> </u>	Ta = -40~85°C		
PARAMETER	SYMBOL	TEST CONDITION		V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	V _{IH}			4.5 \$ 5.5	2.0	_	_	2.0	_	V
Low - Level Input Voltage	VIL			4.5 \$ 5.5	_	_	0.8	_	0.8	V
High - Level Output Voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -50 \mu A$ $I_{OH} = -24 m A$ $I_{OH} = -75 m A*$	4.5 4.5 5.5	4.4 3.94 —	4.5 — —	_ _ _	4.4 3.80 3.85		V
Low - Level Output Voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 50 \mu A$ $I_{OL} = 24 m A$ $I_{OL} = 75 m A*$	4.5 4.5 5.5	_ _ _	0.0 _ _	0.1 0.36 —	_ _ _	0.1 0.44 1.65	V
Input Leakage Current	I _{IN}	$V_{IN} = V_{CC}$ or GN	5.5	_	1	± 0.1	_	± 1.0		
	I _{cc}	$V_{IN} = V_{CC}$ or GND		5.5	_		8.0	_	80.0	μ A
Quiescent Supply Current	I _C	PER INPUT : V _I OTHER INPUT	5.5	_		1.35	_	1.5	mA	

^{*} This spec indicates the capability of driving 50Ω transmission lines. One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF , R_L = 500 Ω , Input t_r = t_f = 3ns)

PARAMETER	CVMBOL	TEST CONDITION		-	Ta = 25°C	:	Ta = -4	UNIT	
PARAIVIETER	SYMBOL		V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	וואוטן
Propagation Delay Time (Cn-Y)	t _{pLH} t _{pHL}		5.0 ± 0.5	I	6.1	9.7	1.0	11.0	
Propagation Delay Time (A,B-Y)	t _{pLH} t _{pHL}		5.0 ± 0.5	I	7.8	11.8	1.0	13.5	ns
Propagation Delay Time $(\overline{G} - Y)$	t _{pLH} t _{pHL}		5.0 ± 0.5	_	5.6	9.7	1.0	11.0	
Input Capacitance	C _{IN}			_	5	10	_	10	pF
Power Dissipation Capacitance	C _{PD} (1)		·	_	47	_	_	_] "

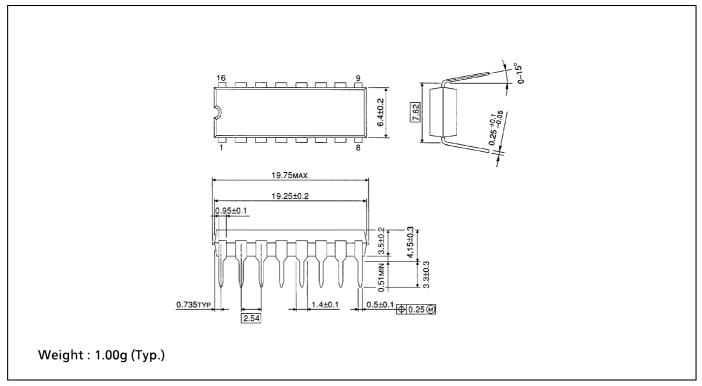
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

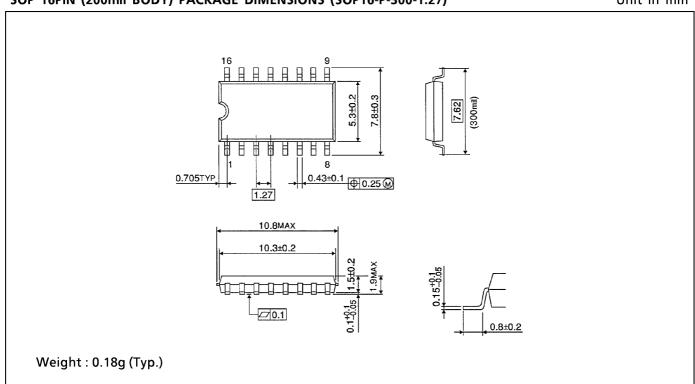
DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



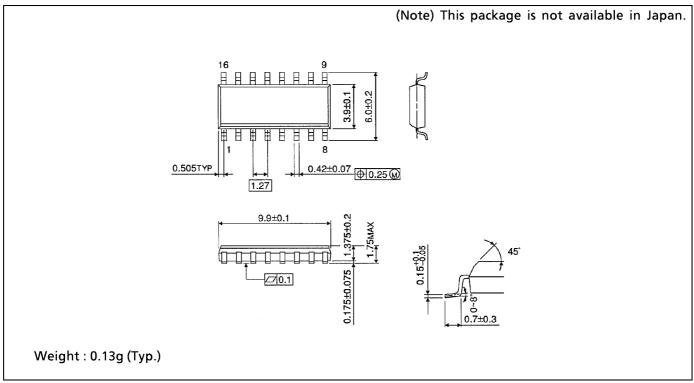
SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



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